

DXT2011P5Q

100V NPN MEDIUM POWER LOW SATURATION TRANSISTOR

Description

This bipolar junction transistor (BJT) is designed to meet the stringent requirement of automotive applications

Mechanical Data

- Case: PowerDI[®]5
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 [®]
- Weight: 0.093 grams (Approximate)

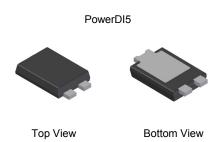
Features

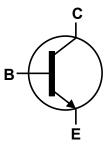
- BV_{CFO} > 100V
- I_C = 6A High Continuous Collector Current
- I_{CM} = 10A Peak Collector Current
- P_D up to 3.2W
- 43% Smaller than SOT223; 60% Smaller than TO252
- Maximum Height just 1.1mm
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DXT2011P5Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

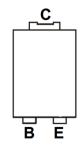
https://www.diodes.com/quality/product-definitions/

Applications

- Motor Drive
- Voltage Regulator Using Emitter-Follower
- DC-DC Converter
- Telecoms
- Power Management







Device Schematic

Pin-Out Top View

Ordering Information (Note 4)

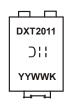
Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXT2011P5Q-13	Automotive	DXT2011	13	16	5000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

PowerDI5





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	200	V
Collector-Emitter Voltage	V _{CEO}	100	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	6	Α
Peak Pulse Current	I _{CM}	10	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit			
	(Note 5)		3.2	W		
Power Dissipation	(Note 6)	P_{D}	1.7			
	(Note 7)		0.74			
	(Note 5)		39	°C/W		
Thermal Resistance, Junction to Ambient Air	(Note 6)	R _{0JA}	75			
	(Note 7)		169			
Thermal Resistance, Junction to Leads (Note 8)		R _{θJL}	5.6			
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C			

ESD Ratings (Note 9)

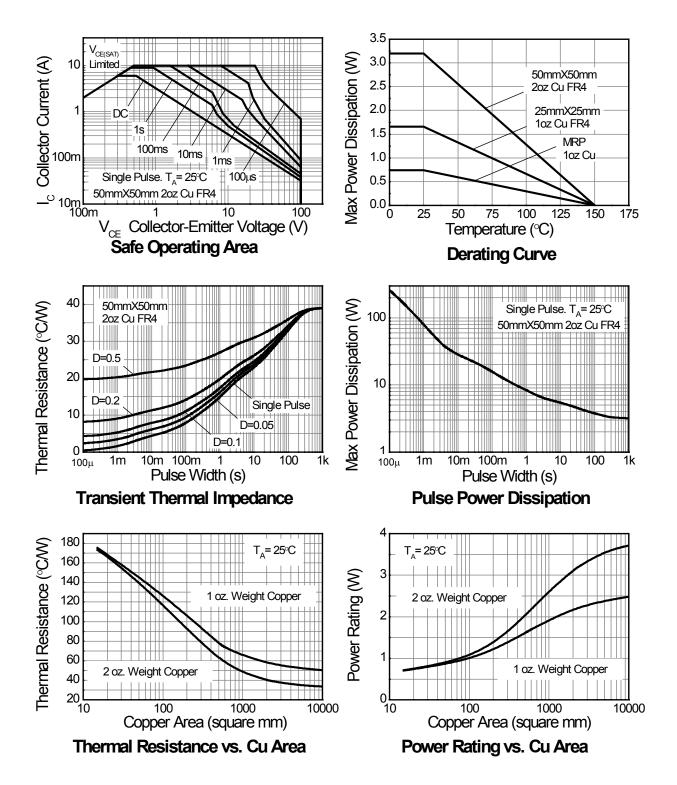
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

- 5. For a device mounted with the exposed collector pad on 50mm × 50mm 2oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- Same as Note 6, except mounted on 25mm × 25mm 1oz copper.
 Same as Note 6, except mounted on minimum recommended pad (MRP) layout.
- 8. Thermal resistance from junction to solder-point (on the exposed collector pad).

 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





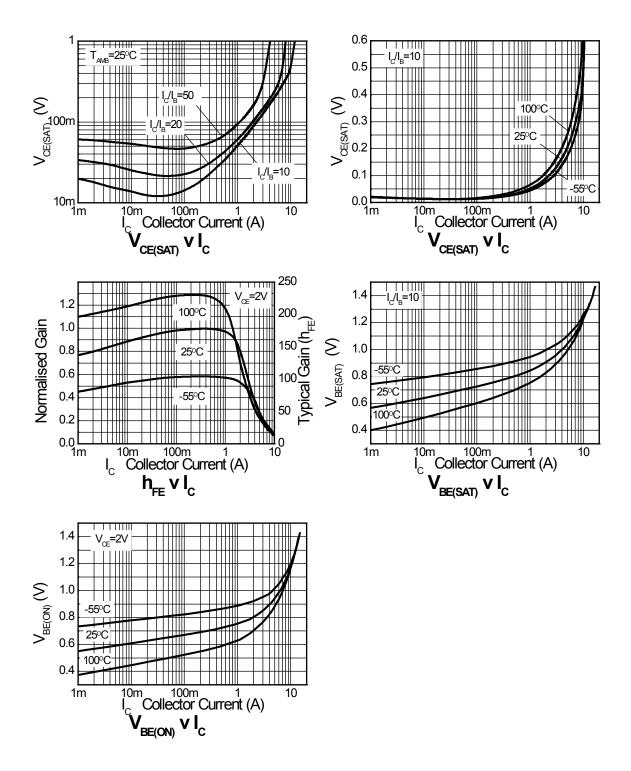
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	200	235	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	100	115	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.1	_	V	I _E = 100μA
Collector Cutoff Current	I _{CBO}	_	_	20	nA	V _{CB} = 150V
Collector Cuton Current		_	_	0.5	μΑ	V _{CB} = 150V, T _A = +100°C
Collector Cutoff Current	I _{CER}	_	_	20	nA	V _{CB} = 150V
Concetor Cuton Current	R≤1kΩ	_	_	0.5	μA	V _{CB} = 150V, T _A = +100°C
Emitter Cutoff Current	I _{EBO}	_		10	nA	V _{EB} = 6V
	V _{CE(sat)}	_	21	35		$I_C = 0.1A$, $I_B = 5mA$
Collector-Emitter Saturation Voltage (Note 10)		_	50	65	mV	I _C = 1A, I _B = 100mA
Solicotor Ennitor Cataration Voltage (Note 10)		_	95	125		I _C = 2A, I _B = 100mA
		_	180	220		$I_C = 5A$, $I_B = 500mA$
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	_	1020	1120	mV	$I_C = 5A$, $I_B = 500mA$
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	_	920	1000	mV	V_{CE} = 2V, I_C = 5A
	h _{FE}	100	_	_	_	V _{CE} = 2V, I _C = 10mA
DC Current Gain (Note 10)		100	_	300	_	$V_{CE} = 2V$, $I_C = 2A$
De current dam (Note 10)		30	_	_	_	$V_{CE} = 2V$, $I_C = 5A$
		10	_	_	_	$V_{CE} = 2V$, $I_C = 10A$
Transition Frequency	f⊤	_	130	-	MHz	V _{CE} = 10V, I _C = 100mA, f = 50MHz
Output Capacitance	C _{obo}	_	26	_	pF	V _{CB} = 10V, f = 1MHz
Switching Times	t _{on}	_	41	_	ne	V _{CC} = 10V, I _C = 1A,
Switching Times	t _{off}	_	1010	_	ns	$I_{B1} = -I_{B2} = 100 \text{mA}$

Note: 10. Pulse Test: Pulse width \leq 300 μ s. Duty cycle \leq 2.0%.



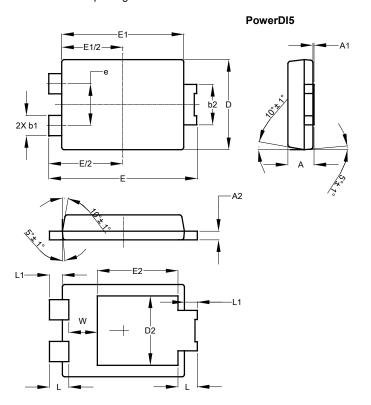
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

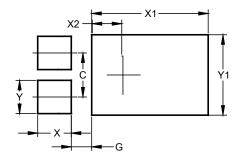


PowerDI5					
Dim	Min	Max	Тур		
Α	1.05	1.15	1.10		
A1	0.00	0.05			
A2	0.33	0.43	0.381		
b1	0.80	0.99	0.89		
b2	1.70	1.88	1.78		
D	3.90	4.05	3.966		
D2			3.054		
Е	6.40	6.60	6.51		
е			1.84		
E1	5.30	5.45	5.37		
E2	-	1	3.549		
L	0.75	0.95	0.85		
L1	0.50	0.65	0.57		
W	1.10	1.41	1.255		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5



Dimensions	Value (in mm)
С	1.840
G	0.852
Х	1.400
X1	4.860
X2	1.310
Y	1.390
Y1	3.360

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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